

AON6407(ES)

Rev-1.6

SuperMOS–PDFN5*6-8L -30V BV_{DSS} , 2.8m Ω $R_{DS(on)}$, P-channel MOSFET

1. Description

The AON6407(ES) is P-channel enhancement MOS Field Effect Transistor. Uses advanced trench technology and design to provide excellent $R_{DS(on)}$ with low gate charge. Device is suitable for use in DC-DC conversion, power switch and charging circuit. Standard Product AON6407(ES) is Pb-free.

2. Features

- -30V, $R_{DS(on)}=2.8m\Omega$ (TYP.) @ $V_{GS}=-10V$
 $R_{DS(on)}=3.8m\Omega$ (TYP.) @ $V_{GS}=-4.5V$
- Use trench MOSFET technology
- High density cell design for low $R_{DS(on)}$
- Material: Halogen free
- Reliable and rugged
- Avalanche Rated
- Low leakage current

3. Applications

- PWM applications
- Load switch
- Power management in portable/desktop PCs
- DC/DC conversion

100% UIS TESTED!

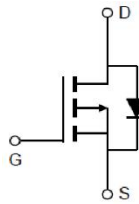
4. Ordering Information

Part Number	Package	Marking	Material	Packing	Quantity per reel	Flammability Rating	Reel Size
AON6407(ES)	PDFN5*6-8L	.N21303C/lot	Halogen free	Tape & Reel	5,000 PCS	UL 94V-0	13 inches

5. Pin Configuration and Functions

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Pin	Function	Outline	Circuit Diagram
4	Gate	Note c 	
1/2/3	Source		
5/6/7/8	Drain		

6. Specification

Absolute Maximum Rating & Thermal Characteristics

Ratings at 25 °C ambient temperature unless otherwise specified.

Parameter		Symbol	Limit	Unit
Drain-Source Voltage		BV_{DSS}	-30	V
Gate-Source Voltage		V_{GS}	± 20	V
Continuous Drain Current	$T_C=25^\circ\text{C}$	I_D	-71.7	A
	$T_C=75^\circ\text{C}$		-55.5	
Maximum Power Dissipation	$T_C=25^\circ\text{C}$	P_D	48.0	W
	$T_C=75^\circ\text{C}$		28.8	
Pulsed Drain Current ^a		I_{DM}	-286.8	A
Avalanche Current, Single Pulsed ^b		I_{AS}	46	A
Avalanche Energy, Single Pulsed ^b		E_{AS}	317	mJ
Operating Junction Temperature		T_J	150	$^\circ\text{C}$
Lead Temperature		T_L	260	$^\circ\text{C}$
Storage Temperature Range		T_{stg}	-55 to 150	$^\circ\text{C}$

Thermal resistance ratings

Single Operation					
Parameter		Symbol	Typ	Max	Unit
Junction-to-Ambient Thermal Resistance	$t \leq 10 \text{ s}$	$R_{\theta JA}$	43	60	$^\circ\text{C/W}$
Junction-to-Case Thermal Resistance	Steady State	$R_{\theta JC}$	1.0	2.6	

Note:

a: Repetitive rating, pulse width limited by junction temperature, $t_p=10\mu\text{s}$, Duty Cycle=1%b: $T_J=25^\circ\text{C}$, $V_{DD}=-30\text{V}$, $V_G=-10\text{V}$, $L=0.3\text{mH}$, $R_g=25\Omega$

c: This diagram is only an electrical schematic, and the actual pin size is based on POD.

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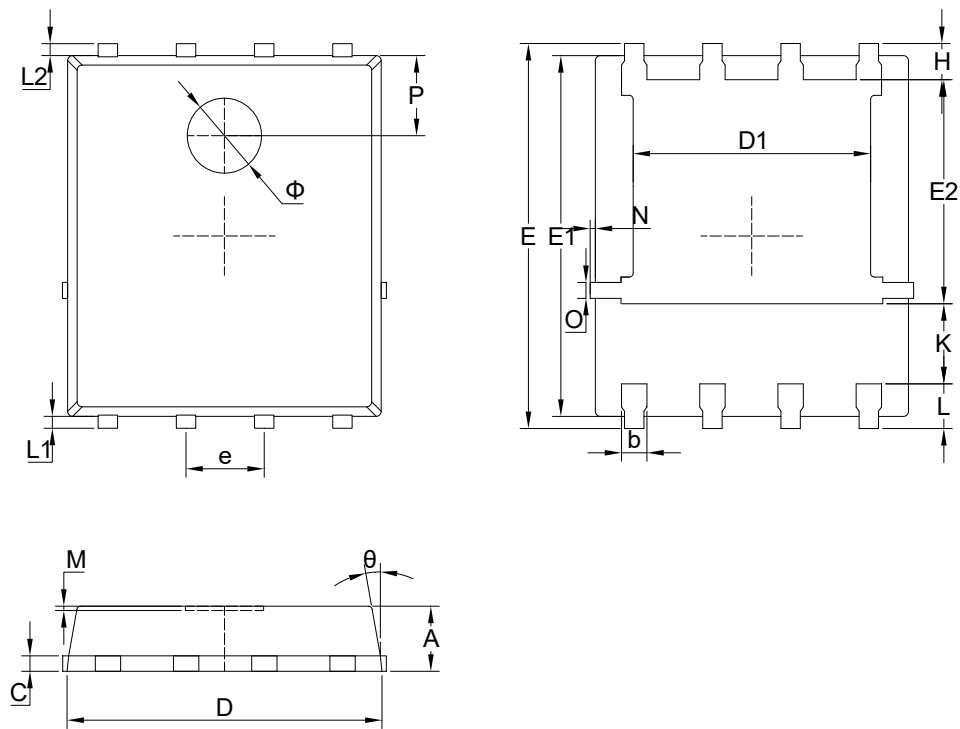
Electrical Characteristics

At TA = 25°C unless otherwise specified

Parameter	Symbol	Test Conditions	Min.	Typ.	Max.	Unit
OFF CHARACTERISTICS						
Drain-to-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V, I _D =-250uA	-30			V
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =-30V, V _{GS} =0V			-1.0	uA
Gate-to-source Leakage Current	I _{GSS}	V _{DS} =0V, V _{GS} =±20V			±100	nA
ON CHARACTERISTICS						
Gate Threshold Voltage	V _{GS(TH)}	V _{GS} =V _{DS} , I _D =-250uA	-1.0	-1.5	-2.0	V
Drain-to-source On-resistance	R _{DS(on)}	V _{GS} =-10V, I _D =-10A		2.8	5.5	mΩ
		V _{DS} =-4.5V, I _D =-10A		3.8	7.2	
CHARGES, CAPACITANCES AND GATE RESISTANCE						
Input Capacitance	C _{ISS}	V _{GS} =0V, f=1MHz, V _{DS} =-15V		3456		pF
Output Capacitance	C _{OSS}			880		
Reverse Transfer Capacitance	C _{RSS}			660		
Total Gate Charge	Q _{G(TOT)}	V _{GS} =-10V, V _{DS} =-15V, I _D =-10A		78		nC
Gate-to-Source Charge	Q _{GS}			12		
Gate-to-Drain Charge	Q _{GD}			45		
SWITCHING CHARACTERISTICS						
Turn-On Delay Time	t _{d(ON)}	V _{GS} =-10V, V _{DS} =-15V, R _L =1Ω, R _G =3Ω		15		ns
Rise Time	t _r			15		
Turn-Off Delay Time	t _{d(OFF)}			95		
Fall Time	t _f			75		
BODY DIODE CHARACTERISTICS						
Forward Voltage	V _{SD}	V _{GS} =0V, I _S =-10A		-0.7	-1.5	V

7. Dimension (PDFN5*6-8L)

POD A(J)

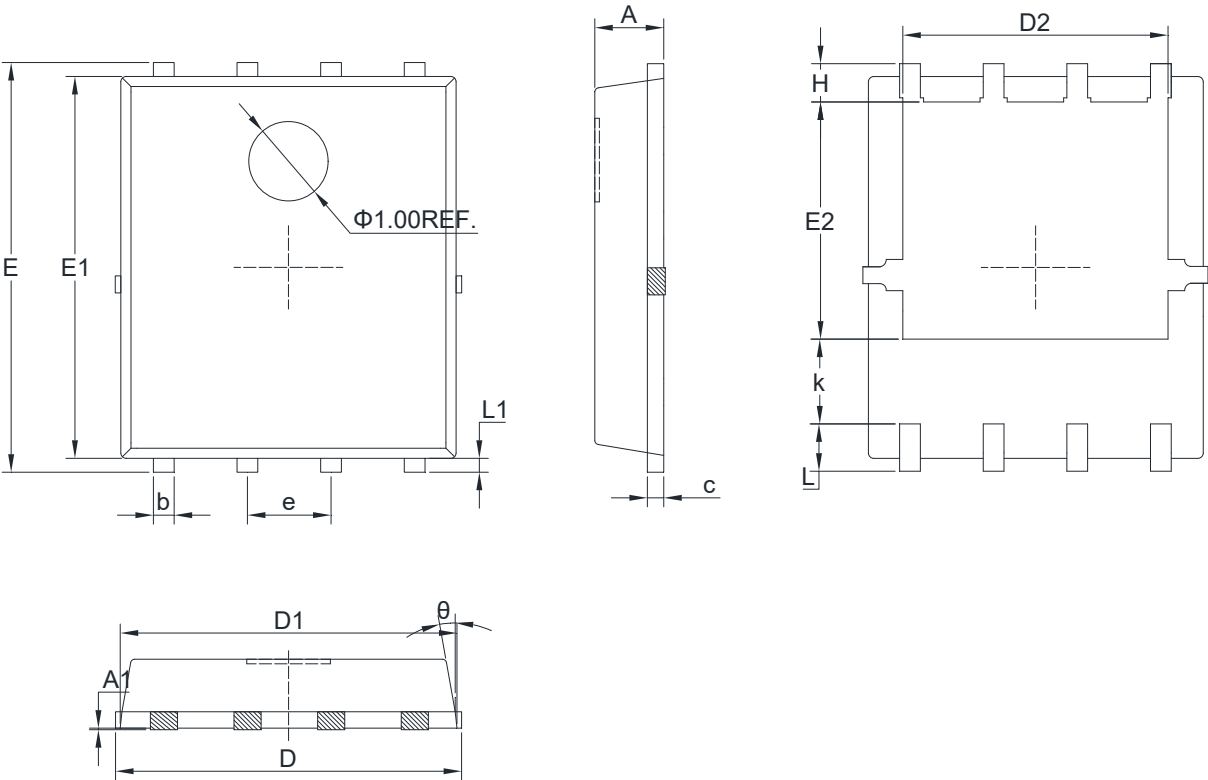


Symbol	Dimensions in Millimeters			Symbol	Dimensions in Millimeters		
	MIN	NOM	MAX		MIN	NOM	MAX
A	0.90	1.05	1.20	H	0.48	0.58	0.68
b	0.35	0.40	0.50	K	1.17	1.27	1.37
C	0.20	0.25	0.35	L	0.64	0.74	0.84
D	4.90	5.05	5.20	L1/L2	0.20 REF.		
D1	3.72	3.82	3.92	θ	8°	10°	12°
E	6.00	6.15	6.30	M	0.08 REF.		
E1	5.60	5.75	5.90	N	0	-	0.15
E2	3.47	3.57	3.67	O	0.25 REF.		
e	1.27 BSC.			P	1.28 REF.		
ϕ	1.20 REF						

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POD B(Q)

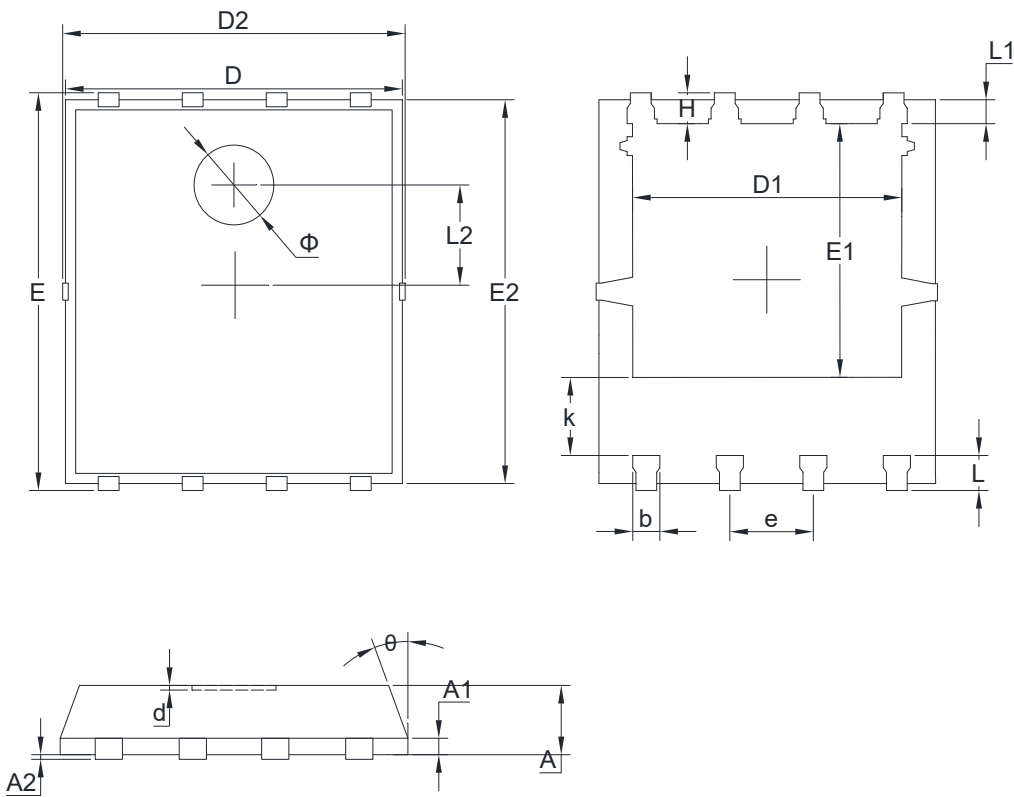


Symbol	Dimensions in Millimeters			Symbol	Dimensions in Millimeters		
	MIN	NOM	MAX		MIN	NOM	MAX
A	0.90	1.00	1.10	H	0.46	0.56	0.66
A1			0.05	k	1.10		
b	0.30	0.40	0.50	L	0.51	0.61	0.71
c	0.20	0.25	0.30	L1	0.05	0.15	0.25
D	4.80	5.10	5.40	θ	8°	10°	12°
D2	3.75	3.90	4.05	D1	4.80	4.90	5.00
E	5.95	6.05	6.15				
E1	5.65	5.75	5.85				
e	1.27BCS						
E2	3.34	3.49	3.64				

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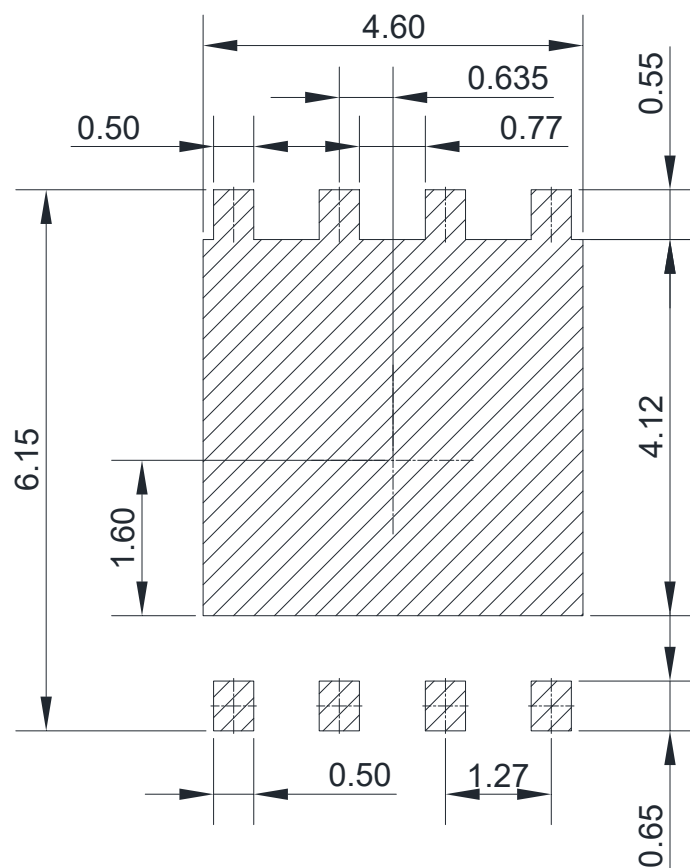
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POD C(X)



Symbol	Dimensions in Millimeters			Symbol	Dimensions in Millimeters		
	MIN	NOM	MAX		MIN	NOM	MAX
A	0.900	1.000	1.100	H	0.549	0.625	0.701
A1	0.254 REF			k	1.190	1.290	1.390
A2	0.000		0.050	L	0.534	0.610	0.686
D	4.824	4.900	4.976	L1	0.424	0.500	0.576
D1	3.910	4.010	4.110	θ	8°	10°	12°
D2	4.924	5.000	5.076	L2	1.800 REF		
E	5.924	6.000	6.076	Φ	1.100	1.200	1.300
E1	3.375	3.475	3.575	d			0.100
e	1.270 TYP			b	0.350	0.400	0.450
E2	5.674	5.750	5.826				

8. Recommended Soldering Footprint



DIMENSIONS: MILLIMETERS

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